Schottky Barrier Diode

NSR0140P2

These Schottky barrier diodes are designed for high-speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand-held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Extremely Low Forward Voltage 0.28 V (Typ) @ I_F = 1.0 mA
- Low Reverse Current
- Lead-Free Plating
- This is a Pb-Free Device

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RM}	40	V
Continuous Reverse Voltage (DC)	V_{R}	30	V
Continuous Forward Current (DC)	I _F	70	mA
Non-Repetitive Peak Forward Surge Current	I _{FSM}	500	mA
ESD Rating: Class 1C per Human Body Mode Class A per Machine Model	ıl		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C	P _D	100	mW
Derate above 25°C		1.0	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	1000	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +125	°C

1

1. FR-5 Minimum Pad.

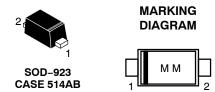


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40 V SCHOTTKY BARRIER DIODE





M = Specific Device Code*
 (Character is rotated 270° clockwise)
 M = Month Code

ORDERING INFORMATION

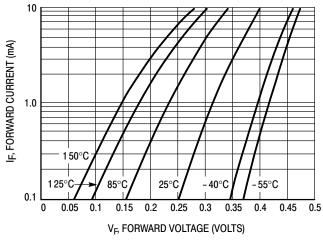
Device	Package	Shipping†
NSR0140P2T5G	SOD-923 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NSR0140P2

$\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}C \ unless \ otherwise \ noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage $(I_R = 10 \mu A)$	V _{(BR)R}	30	-	-	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	СТ	-	2.0	2.5	pF
Reverse Leakage (V _R = 30 V)	I _R	-	300	500	nA
Forward Voltage (I _F = 1.0 mA)	V _F	-	0.28	0.35	V



1000 $T_A = 150^{\circ}C$ I_R, REVERSE CURRENT (μA) 100 125°C 10 85°C 1.0 0.1 25°C 0.01 0.001 0 15 20 25 35 V_R, REVERSE VOLTAGE (VOLTS)

Figure 1. Typical Forward Voltage

Figure 2. Reverse Current versus Reverse Voltage

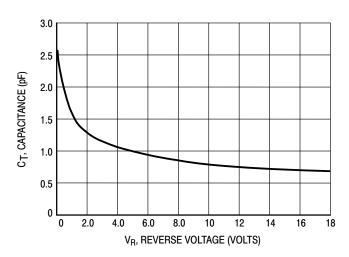


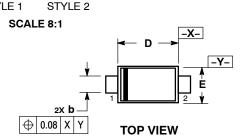
Figure 3. Typical Capacitance

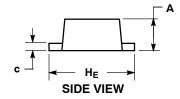


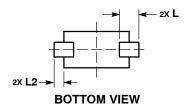


SOD-923 CASE 514AB ISSUE D

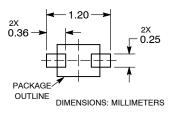
DATE 03 SEP 2020







SOLDERING FOOTPRINT*



See Application Note AND8455/D for more mounting details

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

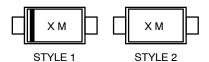
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD MAXIMUM LEAD I HICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

 DIMENSION L WILL NOT EXCEED 0.30mm.

	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	MOM	MAX
Α	0.34	0.37	0.40	0.013	0.015	0.016
b	0.15	0.20	0.25	0.006	800.0	0.010
С	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.031	0.033
Е	0.55	0.60	0.65	0.022	0.024	0.026
HE	0.95	1.00	1.05	0.037	0.039	0.041
L	().19 REI	F	0	.007 RE	F
L2	0.05	0.10	0.15	0.002	0.004	0.006

GENERIC MARKING DIAGRAM*



Χ = Specific Device Code

= Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 2: NO POLARITY STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE

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DESCRIPTION:	ON: SOD-923, 1.0X0.6X0.37, MAX HEIGHT 0.40		PAGE 1 OF 1	

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